SIEMENS

Data sheet 3RF2120-1AA22



Semiconductor relay, 1-phase 3RF2 Width 22.5 mm, 20 A 24-230 V / 110-230 V AC screw terminal

product brand name	SIRIUS
product designation	solid-state relay
design of the product	single-phase
product type designation	3RF21
manufacturer's article number	
_1 of the accessories that can be ordered	3RF2900-3PA88
_2 of the accessories that can be ordered	3RF2920-0HA33
 _4 of the accessories that can be ordered 	3RF2920-0GA33
product designation	
_1 of the accessories that can be ordered	terminal cover
_2 of the accessories that can be ordered	power regulator
_4 of the accessories that can be ordered	load monitoring
General technical data	
product function	zero-point switching
power loss [V·A] maximum	28.6 VA
power loss [W] for rated value of the current	
 at AC in hot operating state 	28.6 W
 at AC in hot operating state per pole 	28.6 W
without load current share typical	3.5 W
insulation voltage rated value	600 V
type of voltage	
 of the operating voltage 	AC
of the control supply voltage	AC
surge voltage resistance of main circuit rated value	6 kV
shock resistance according to IEC 60068-2-27	15g / 11 ms
vibration resistance according to IEC 60068-2-6	2g
reference code according to EN 61346-2	Q
reference code according to IEC 81346-2	Q
Substance Prohibitance (Date)	05/28/2009
Main circuit	
number of poles for main current circuit	1
number of NO contacts for main contacts	1
number of NC contacts for main contacts	0
type of voltage of the operating voltage	AC
operating voltage	
• at AC	
— at 50 Hz rated value	24 230 V
— at 60 Hz rated value	24 230 V
operating frequency rated value	50 60 Hz
relative symmetrical tolerance of the operating frequency	10 %

operating range relative to the operating voltage at AC	
● at 50 Hz	20 253 V
● at 60 Hz	20 253 V
operational current	
 at AC-51 rated value 	20 A
 according to UL 508 rated value 	20 A
ampacity maximum	20 A
operational current minimum	100 mA
rate of voltage rise at the thyristor for main contacts maximum permissible	500 V/μs
blocking voltage at the thyristor for main contacts maximum permissible	800 V
reverse current of the thyristor	10 mA
derating temperature	40 °C
surge current resistance rated value	200 A
I2t value maximum	200 A²·s
Control circuit/ Control	
type of voltage of the control supply voltage	AC
control supply voltage 1 at AC	
• at 50 Hz	110 230 V
• at 60 Hz	110 230 V
control supply voltage frequency	
• 1 rated value	50 Hz
• 2 rated value	60 Hz
control supply voltage at AC	
at 50 Hz full-scale value for signal<0> recognition	40 V
at 60 Hz full-scale value for signal<0> recognition	40 V
control supply voltage	40 V
at AC initial value for signal <1> detection	90 V
	5 Hz
symmetrical line frequency tolerance	5 HZ
control current at minimum control supply voltage • at AC	2 mA
	15 mA
control current at AC rated value	
ON-delay time	40 ms; additionally max. one half-wave
OFF-delay time	40 ms; additionally max. one half-wave
Auxiliary circuit	
number of NC contacts for auxiliary contacts	0
number of NO contacts for auxiliary contacts	0
number of CO contacts for auxiliary contacts	0
Installation/ mounting/ dimensions	
fastening method	screw fixing
side-by-side mounting	Yes
design of the thread of the screw for securing the equipment	M4
tightening torque of fixing screw maximum	1.5 N·m
tightening torque [lbf·in] of fixing screw maximum	13 lbf-in
height	85 mm
width	22.5 mm
depth	48 mm
Connections/ Terminals	
product component removable terminal for auxiliary and control circuit	Yes
type of electrical connection	
• for main current circuit	screw-type terminals
for auxiliary and control circuit	screw-type terminals
type of connectable conductor cross-sections	
• for main contacts	
— solid	2x (1.5 2.5 mm²), 2x (2.5 6 mm²)
finely stranded with core end processing	2x (1 2.5 mm²), 2x (2.5 6 mm²), 1x 10 mm²
for AWG cables for main contacts	2x (14 10)
connectable conductor cross-section for main contacts	(············)
	1.5 6 mm ²
solid or stranded	1.5 6 mm²

finely stranded with core end processing	1 10 mm²
type of connectable conductor cross-sections	
 for auxiliary and control contacts 	
— solid	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded with core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 finely stranded without core end processing 	1x (0.5 2.5 mm²), 2x (0.5 1.0 mm²)
 for AWG cables for auxiliary and control contacts 	1x (AWG 20 12)
AWG number as coded connectable conductor cross section for main contacts	14 10
tightening torque	
 for main contacts with screw-type terminals 	2 2.5 N·m
 for auxiliary and control contacts with screw-type terminals 	0.5 0.6 N·m
tightening torque [lbf·in]	
 for main contacts with screw-type terminals 	7 10.3 lbf·in
 for auxiliary and control contacts with screw-type terminals 	4.5 5.3 lbf-in
design of the thread of the connection screw	
• for main contacts	M4
of the auxiliary and control contacts	M3
stripped length of the cable	
• for main contacts	7 mm
for auxiliary and control contacts	7 mm
Safety related data	
protection class IP on the front according to IEC 60529	IP20
touch protection on the front according to IEC 60529	finger-safe, for vertical contact from the front
Ambient conditions	
installation altitude at height above sea level maximum	1 000 m
ambient temperature	
during operation	-25 +60 °C
during storage	-55 +80 °C
Electromagnetic compatibility	
conducted interference	
oonadoted interioreile	
• due to burst according to IEC 61000 4.4	2 kV / 5 kHz behavior criterion 2
due to burst according to IEC 61000-4-4 due to conductor earth surge according to IEC 61000 4.5.	2 kV / 5 kHz behavior criterion 2
• due to conductor-earth surge according to IEC 61000-4-5	2 kV behavior criterion 2
· ·	
 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 	2 kV behavior criterion 2
 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000- 	2 kV behavior criterion 2 1 kV behavior criterion 2
 due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1
due to conductor-earth surge according to IEC 61000-4-5 due to conductor-conductor surge according to IEC 61000-4-5 due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-8 • dield-based interference according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 • field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at NH design usable • of back-up R fuse link for semiconductor protection at	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-8 • due to high-frequency radiation according to IEC 61000-4-3 • delectrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1 3NC1032
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-8 • due to high-frequency radiation according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 field-based interference according to IEC 61000-4-3 electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 12 x 58 mm usable manufacturer's article number of the gG fuse	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430 3NC2225
• due to conductor-earth surge according to IEC 61000-4-5 • due to conductor-conductor surge according to IEC 61000-4-5 • due to high-frequency radiation according to IEC 61000-4-6 • due to high-frequency radiation according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-3 • electrostatic discharge according to IEC 61000-4-2 conducted HF interference emissions according to CISPR11 field-bound HF interference emission according to CISPR11 Short-circuit protection, design of the fuse link manufacturer's article number • of gS fuse for semiconductor protection at NH design usable • of full range R fuse link for semiconductor protection at cylindrical design usable • of back-up R fuse link for semiconductor protection at cylindrical design 10 x 38 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 14 x 51 mm usable • of back-up R fuse link for semiconductor protection at cylindrical design 22 x 58 mm usable manufacturer's article number of the gG fuse • at NH design usable	2 kV behavior criterion 2 1 kV behavior criterion 2 140 dBuV in the frequency range 0.15 80 MHz, behavior criterion 1 80 MHz 1 GHz 10 V/m, behavior criterion 1 4 kV contact discharging / 8 kV air discharging, behavior criterion 2 Class A for industrial environment Class B for the domestic, business and commercial environments 3NE1814-0 5SE1325 3NE8015-1 3NC1032 3NC1430 3NC2225 3NA6803; These fuses have a smaller rated current than the semiconductor relays 3NW6001-1; These fuses have a smaller rated current than the semiconductor

manufacturer's article number

of NEOZED fuse usable

5SE2306; These fuses have a smaller rated current than the semiconductor relavs

Certificates/ approvals

General Product Approval

EMC

Declaration of Conformity



Confirmation



EAC





Declaration of Conformity

Test Certificates

other

Railway



Special Test Certificate

Type Test Certificates/Test Report

Confirmation



Vibration and Shock

Further information

Siemens has decided to exit the Russian market (see here).

https://press.siemens.com/global/en/pressrelease/siemens-wind-down-russian-business

Siemens is working on the renewal of the current EAC certificates.

Please contact your local Siemens office on the status of validity of the EAC certification if you intend to import or offer to supply these products to an EAC relevant market (other than the sanctioned EAEU member states Russia or Belarus).

Information on the packaging

https://support.industry.siemens.com/cs/ww/en/view/109813875

Information- and Downloadcenter (Catalogs, Brochures,...)

https://www.siemens.com/ic10

Industry Mall (Online ordering system)

https://mall.industry.siemens.com/mall/en/en/Catalog/product?mlfb=3RF2120-1AA22

Cax online generator

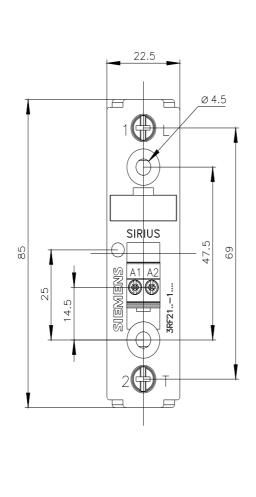
http://support.automation.siemens.com/WW/CAXorder/default.aspx?lang=en&mlfb=3RF2120-1AA22

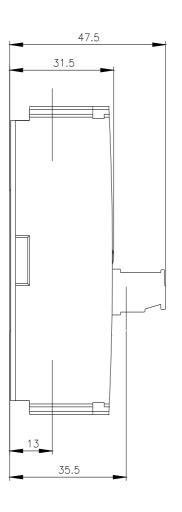
Service&Support (Manuals, Certificates, Characteristics, FAQs,...)

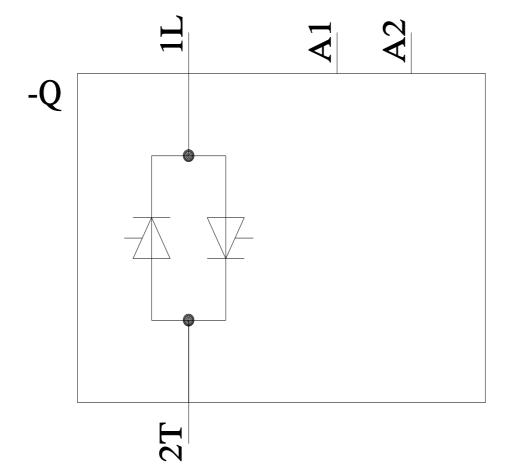
https://support.industry.siemens.com/cs/ww/en/ps/3RF2120-1AA22

Image database (product images, 2D dimension drawings, 3D models, device circuit diagrams, EPLAN macros, ...)

http://www.automation.siemens.com/bilddb/cax_de.aspx?mlfb=3RF2120-1AA22&lang=en







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